### **High Performance Schottky Rectifier New Generation 3** D-61 Package, 2 x 55 A

Base

common cathode

62

Common

cathode

32 mA at 125 °C

175 °C

Common cathode 15 mJ

3

Anode

2

61 δЗ 52 Anode Common Anode cathode 2 D-61-8-SM Base VS-113CNQ100ASLPbF common cathode 01 3 Anode Anode 2 1 D-61-8-SL **PRODUCT SUMMARY** Package D-61-8, D-61-8-SM, D-61-8-SL 2 x 55 A I<sub>F(AV)</sub> 100 V  $V_R$ 0.81 V  $V_F$  at  $I_F$ 

Anode

1

### **FEATURES**

- 175 °C T<sub>J</sub> operation
- · Center tap module
- · Low forward voltage drop
- High frequency operation
- High power discrete
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- · New fully transfer-mold low profile, small footprint, high current package
- · Designed and qualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### Note

This datasheet provides information about parts that are RoHS-compliant and/or parts that are non-RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information/tables in this datasheet for details.

### DESCRIPTION

The center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	110	A			
V <sub>RRM</sub>		100	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	7000	A			
V <sub>F</sub>	55 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.66	V			
TJ	Range	-55 to +175	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-113CNQ100APbF	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	100	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	100	v			

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D-61-8

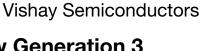
#### VS-113CNQ100ASMPbF



I<sub>RM</sub> max. T<sub>J</sub> max.

Diode variation

E<sub>AS</sub>





VS-113CNQ100APbF

ISHA





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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average per leg		$I_{F(AV)}$ 50 % duty cycle at T <sub>C</sub> = 150 °C, rectangular waveform		55	А	
See fig. 5	per device	I <sub>F(AV)</sub>	$50\%$ duty cycle at $T_{\rm C} = 150\%$ C, rectangular wavelonn		110	~
Maximum peak one cycle non-repetitive surge current per leg See fig. 7		I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	7000	A
			10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	720	
Non-repetitive avalanche energy per leg		E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 30 mH		15	mJ
Repetitive avalanche current per leg		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu s$ Frequency limited by $T_J$ maximum $V_A$ = 1.5 x $V_R$ typical		1	А

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
	V <sub>FM</sub> <sup>(1)</sup>	55 A	T <sub>.1</sub> = 25 °C	0.81	V	
Maximum forward voltage drop per leg		110 A	1j=25 C	1.00		
See fig. 1		55 A	T - 105 °C	0.66		
		110 A	T <sub>J</sub> = 125 °C	0.79		
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>B</sub>	1.0	mA	
See fig. 2		T <sub>J</sub> = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	32		
Maximum junction capacitance per leg	CT	$V_R$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		1960	pF	
Typical series inductance per leg	Ls	Measured lead to lead 5 mm from package body		5.5	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs	

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C	
Maximum thermal resistance, junction to case per leg		D	DC operation See fig. 4	0.5	°C/W	
Maximum thermal resistance, junction to case per package		R <sub>thJC</sub>	DC operation	0.25		
Typical thermal resistance, case to heatsink (D-61-8 only)		R <sub>thCS</sub>	Mounting surface, smooth and greased Device flatness < 5 mils	0.30		
Approximate weight				7.8	g	
				0.28	oz.	
Mounting torque minimum			Recommended hardware 3M stainless screw	12 (10)	kgf ⋅ cm	
(D-61-8 only)	maximum		Recommended hardware SWI stainless screw	24 (20)	(lbf · in)	
Marking device			Case style D-61-8	113CNQ100A		
			Case style D-61-8-SM	113CNQ	100ASM	
			Case style D-61-8-SL	113CNQ	100ASL	

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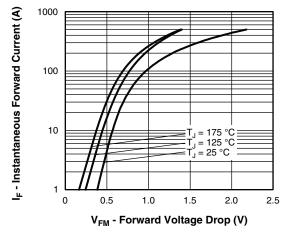
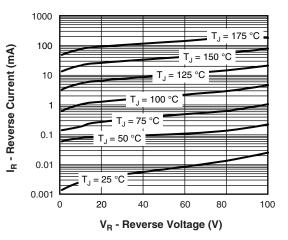
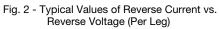


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)





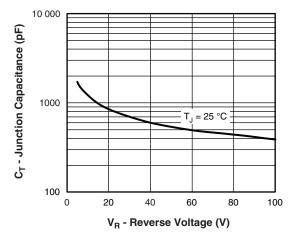
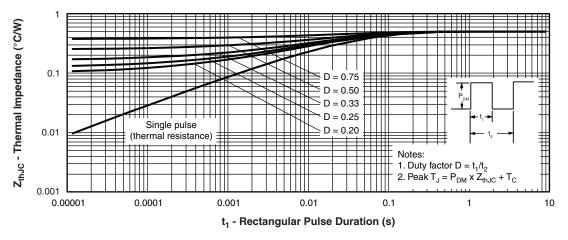
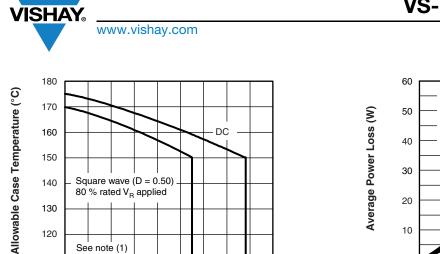


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

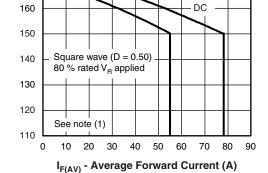


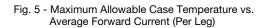


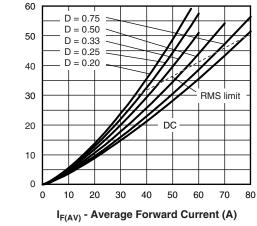
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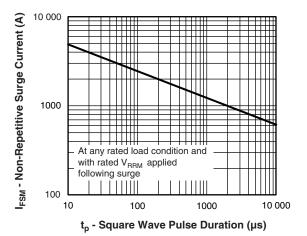


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

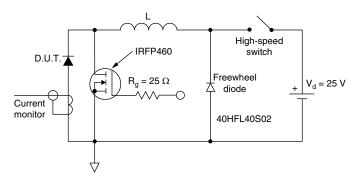


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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### **ORDERING INFORMATION TABLE**

Device code	VS-	113	С	N	Q	100	Α	PbF
	1	2	3	4	5	6	7	8
	1 -   2 -   3 -   3 -   4 -   5 -   6 -   7 -	Curr C = Pac N = Sch Volt Pac • A • AS	rent ratii uit confi commo kage: D-61 ottky "Q age ratii kage sty = D-61-6 SM = D-6	ng (100 /le: 8 61-8-SM 61-8-SL	A) i: de = 100 V	/)	-	
	8 -			andard µ d (Pb)-fr		ion		

Standard pack quantity: A = 10 pieces; ASM/ASL = 20 pieces

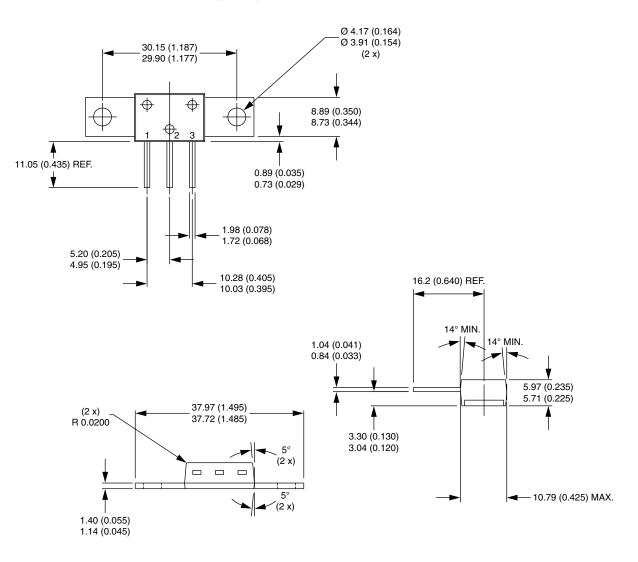
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95354					
Part marking information	www.vishay.com/doc?95356					

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D-61-8, D-61-8-SM, D-61-8-SL

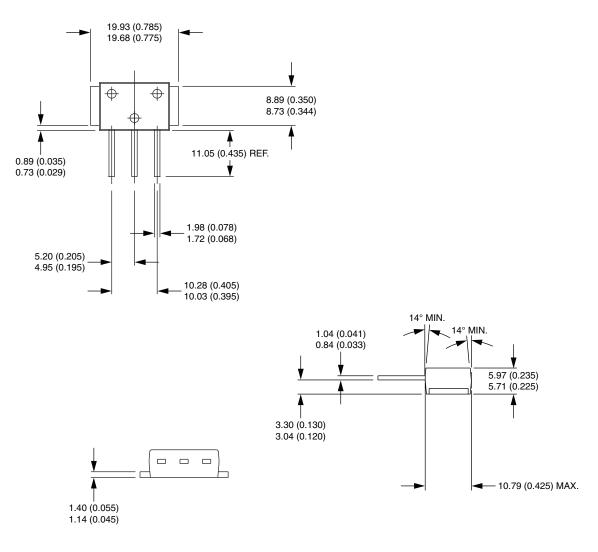
### DIMENSIONS - D-61-8 in millimeters (inches)





### DIMENSIONS - D-61-8-SM in millimeters (inches)

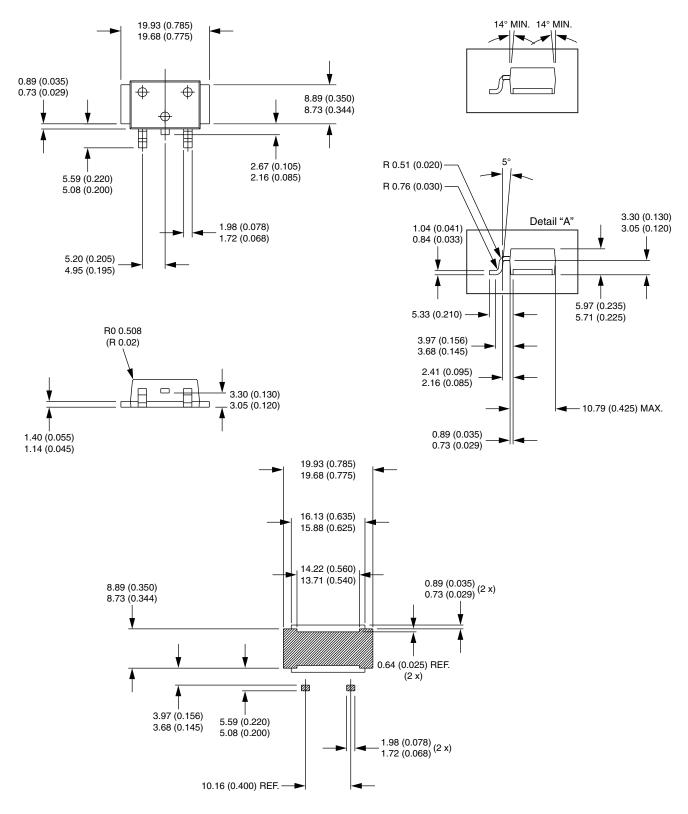
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### DIMENSIONS - D-61-8-SL in millimeters (inches)

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